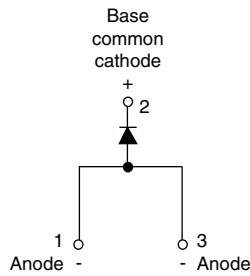




## Surface Mountable Fast Soft Recovery Diode, 8 A



D-PAK



### FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition



RoHS COMPLIANT HALOGEN FREE

### APPLICATIONS

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

### DESCRIPTION

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

PRODUCT SUMMARY	
Package	D-PAK (TO-252AA)
$I_{F(AV)}$	8 A
$V_R$	200 V, 400 V, 600 V
$V_F$ at $I_F$	1.2 V
$I_{FSM}$	120 A
$t_{rr}$	55 ns
Diode variation	Single die
Snap	0.5

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	8	A
$V_{RRM}$		200 to 600	V
$I_{FSM}$		120	A
$V_F$	8 A, $T_J = 25\text{ °C}$	1.2	V
$t_{rr}$	1 A, 100 A/ $\mu$ s	55	ns
$T_J$	Range	- 40 to 150	°C

VOLTAGE RATINGS			
PART NUMBER	$V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ AT 150 °C mA
VS-8EWF02S-M3	200	300	3
VS-8EWF04S-M3	400	500	
VS-8EWF06S-M3	600	700	

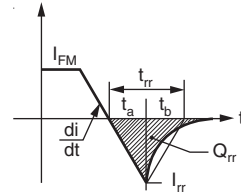
ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 96\text{ °C}$ , 180° conduction half sine wave	8	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}^{(1)}$	10 ms sine pulse, rated $V_{RRM}$ applied	101	
		10 ms sine pulse, no voltage reapplied	120	
Maximum $I^2t$ for fusing	$I^2t$	10 ms sine pulse, rated $V_{RRM}$ applied	51	A <sup>2</sup> s
		10 ms sine pulse, no voltage reapplied	72	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1\text{ ms to }10\text{ ms}$ , no voltage reapplied	510	A <sup>2</sup> $\sqrt{s}$

### Note

(1) Connecting one pin only.

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	8 A, $T_J = 25\text{ }^\circ\text{C}$		1.2	V
Forward slope resistance	$r_t$	$T_J = 150\text{ }^\circ\text{C}$		16	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$			1.13	V
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_{RRM}$	0.1	mA
		$T_J = 150\text{ }^\circ\text{C}$		3	

RECOVERY CHARACTERISTICS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	$t_{rr}$	$I_F$ at 1 Apk 100 A/ $\mu\text{s}$ $T_J = 25\text{ }^\circ\text{C}$	55	ns
		$I_F$ at 8 Apk 25 A/ $\mu\text{s}$ $T_J = 25\text{ }^\circ\text{C}$	140	
Reverse recovery current	$I_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	2.6	A
Reverse recovery charge	$Q_{rr}$		0.25	$\mu\text{C}$
Snap factor	S		0.5	



THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		- 40 to 150	$^\circ\text{C}$
Soldering temperature	$T_S$	For 10 seconds	240	
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation	2.5	$^\circ\text{C}/\text{W}$
Typical thermal resistance, junction to ambient (PCB mount)	$R_{thJA}^{(1)}$		50	
Approximate weight			1	g
			0.03	oz.
Marking device		Case style TO-252AA (D-PAK)	8EWF02S	
			8EWF04S	
			8EWF06S	

**Note**

<sup>(1)</sup> When mounted on 1" square (650 mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz. (140  $\mu\text{m}$ ) copper 40  $^\circ\text{C}/\text{W}$   
For recommended footprint and soldering techniques refer to application note #AN-994



# VS-8EWF02S-M3, VS-8EWF04S-M3, VS-8EWF06S-M3

Surface Mountable Fast Soft  
Recovery Diode, 8 A

Vishay Semiconductors

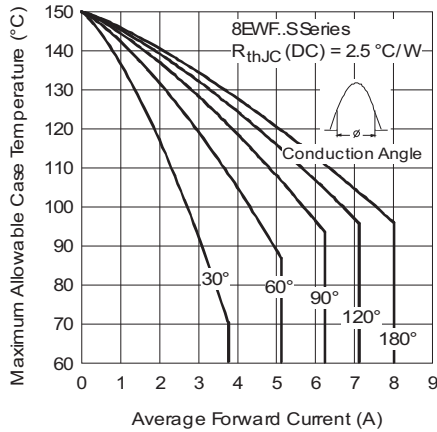


Fig. 1 - Current Rating Characteristics

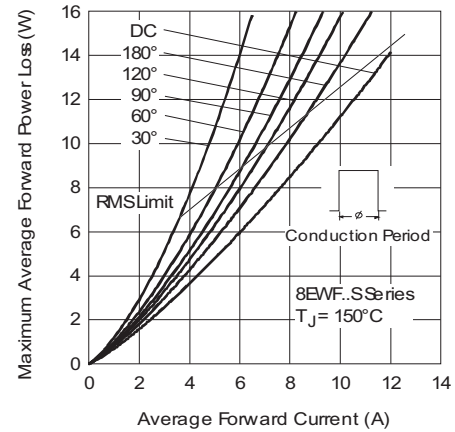


Fig. 4 - Forward Power Loss Characteristics

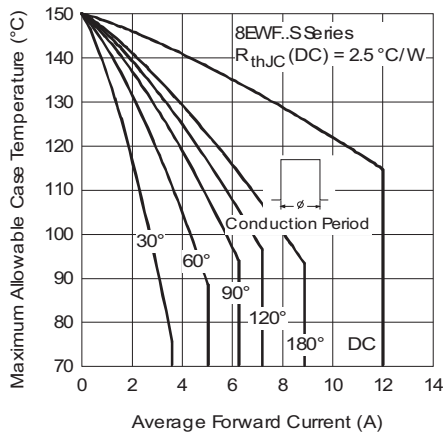


Fig. 2 - Current Rating Characteristics

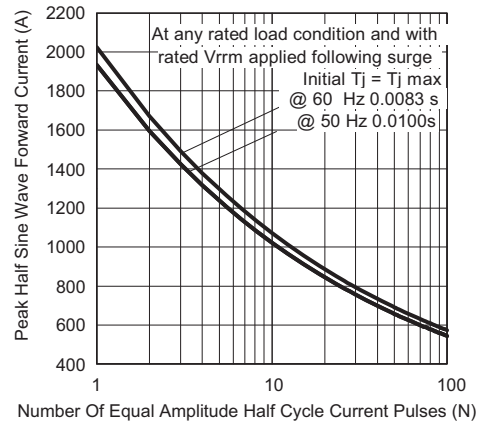


Fig. 5 - Maximum Non-Repetitive Surge Current

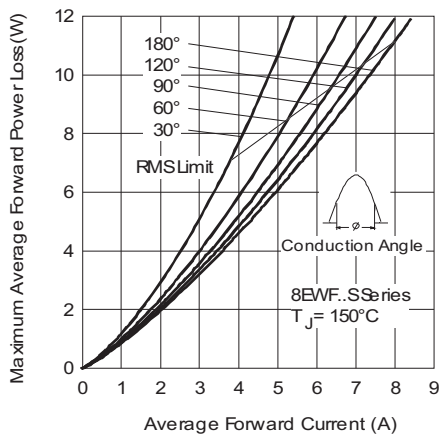


Fig. 3 - Forward Power Loss Characteristics

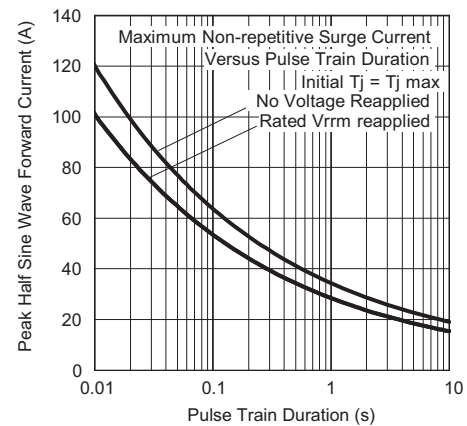


Fig. 6 - Maximum Non-Repetitive Surge Current

# VS-8EWF02S-M3, VS-8EWF04S-M3, VS-8EWF06S-M3



Vishay Semiconductors

Surface Mountable Fast Soft  
Recovery Diode, 8 A

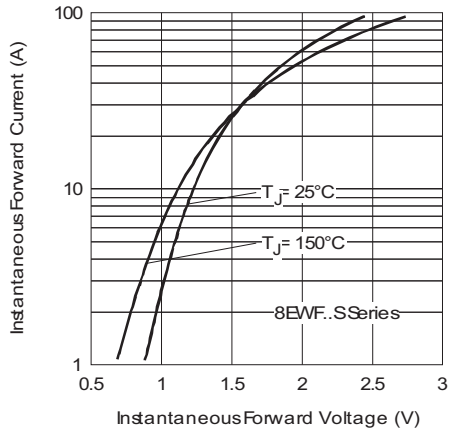


Fig. 7 - Forward Voltage Drop Characteristics

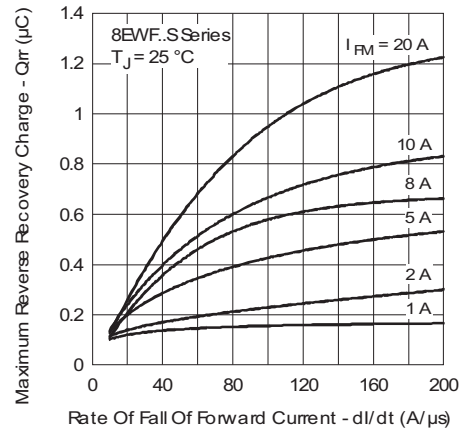


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25\text{ }^\circ\text{C}$

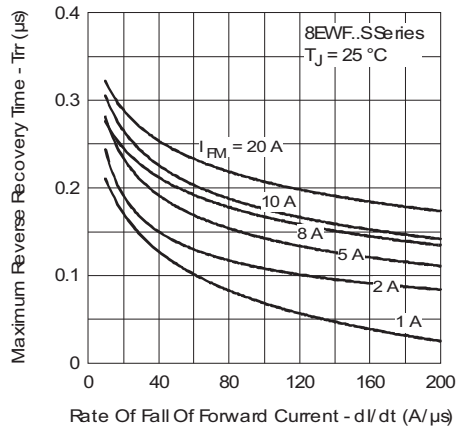


Fig. 8 - Recovery Time Characteristics,  $T_J = 25\text{ }^\circ\text{C}$

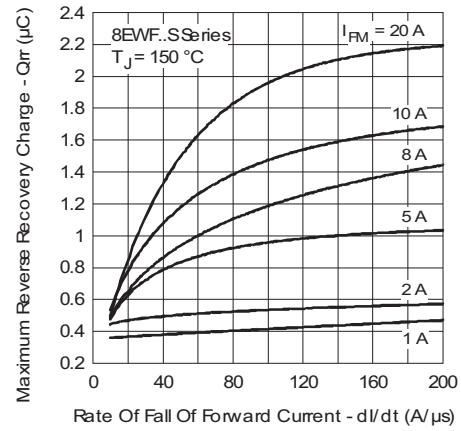


Fig. 11 - Recovery Charge Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

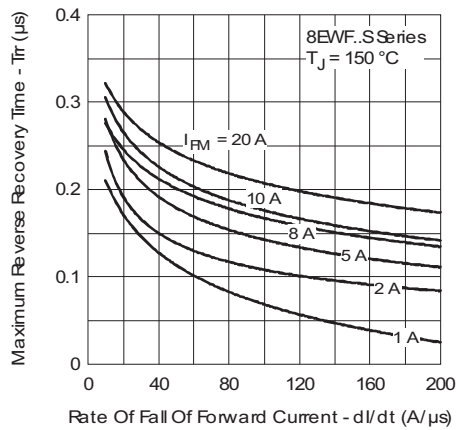


Fig. 9 - Recovery Time Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

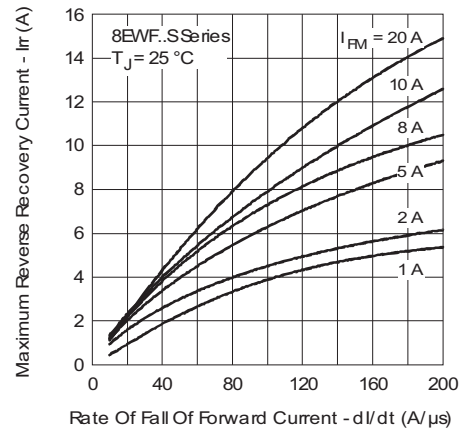


Fig. 12 - Recovery Current Characteristics,  $T_J = 25\text{ }^\circ\text{C}$



# VS-8EWF02S-M3, VS-8EWF04S-M3, VS-8EWF06S-M3

Surface Mountable Fast Soft  
Recovery Diode, 8 A

Vishay Semiconductors

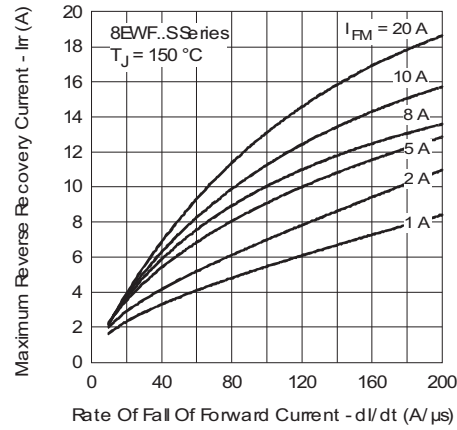


Fig. 13 - Recovery Current Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

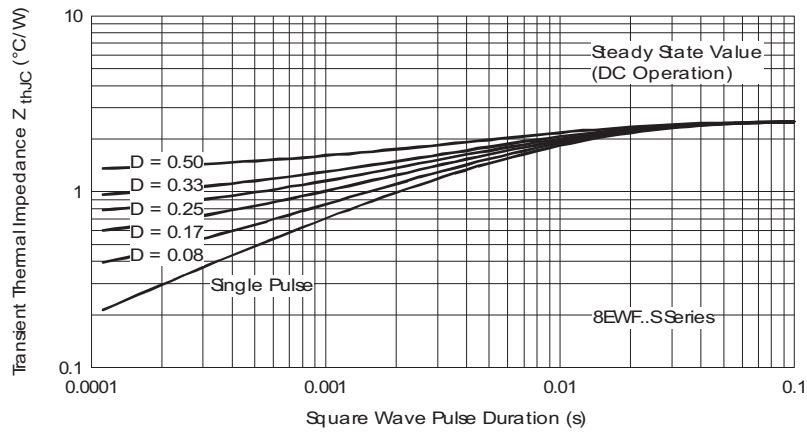


Fig. 14 - Thermal Impedance  $Z_{thJC}$  Characteristics

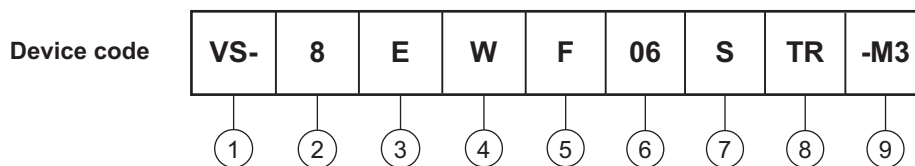
# VS-8EWF02S-M3, VS-8EWF04S-M3, VS-8EWF06S-M3



Vishay Semiconductors

Surface Mountable Fast Soft  
Recovery Diode, 8 A

## ORDERING INFORMATION TABLE



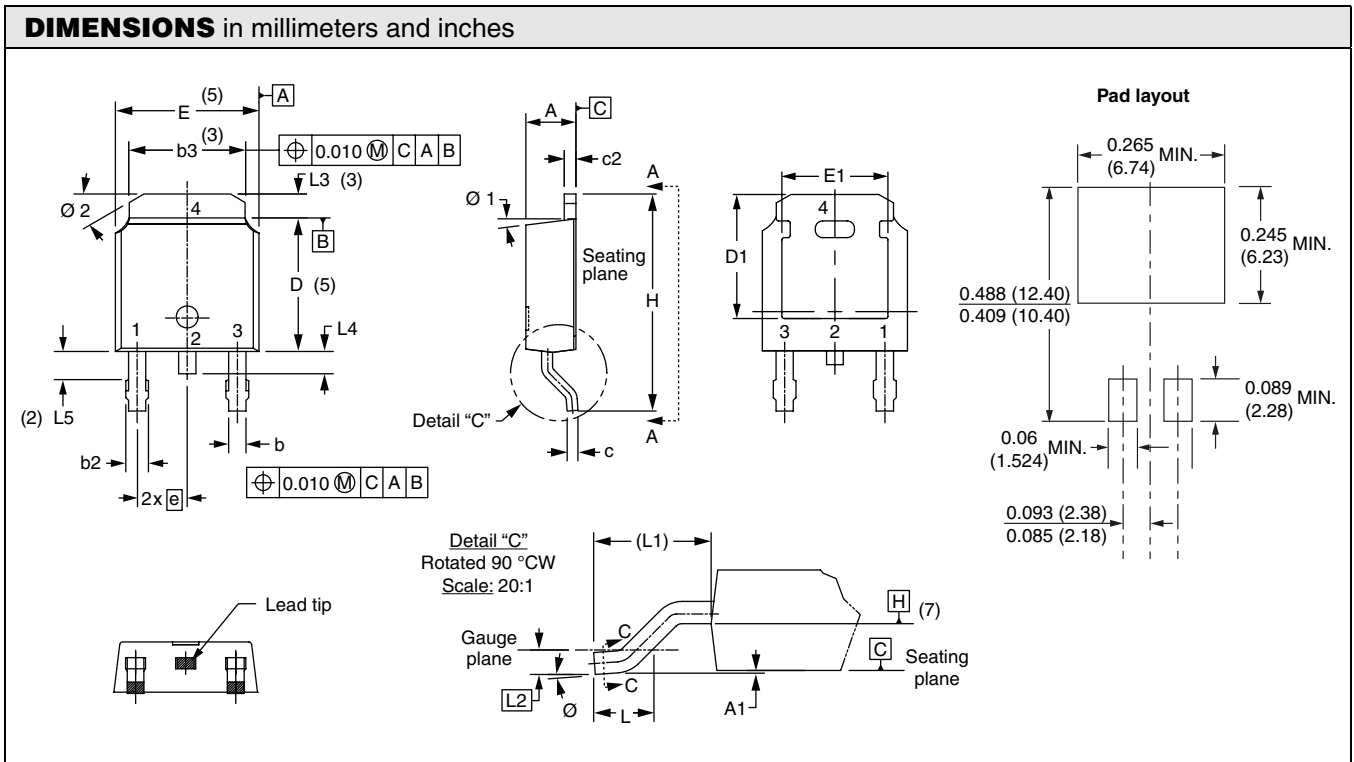
- 1** - Vishay Semiconductors product
- 2** - Current rating (8 = 8 A)
- 3** - Circuit configuration:  
E = Single diode
- 4** - Package:  
W = D-PAK
- 5** - Type of silicon:  
F = Fast soft recovery rectifier
- 6** - Voltage code x 100 =  $V_{RRM}$ 

02 = 200 V
04 = 400 V
06 = 600 V
- 7** - S = Surface mountable
- 8** -
  - TR = Tape and reel
  - TRR = Tape and reel (right oriented)
  - TRL = Tape and reel (left oriented)
- 9** - Environmental digit:  
-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-8EWF02S-M3	75	3000	Antistatic plastic tubes
VS-8EWF02STR-M3	2000	2000	13" diameter reel
VS-8EWF02STRL-M3	3000	3000	13" diameter reel
VS-8EWF02STRR-M3	3000	3000	13" diameter reel
VS-8EWF04S-M3	75	3000	Antistatic plastic tubes
VS-8EWF04STR-M3	2000	2000	13" diameter reel
VS-8EWF04STRL-M3	3000	3000	13" diameter reel
VS-8EWF04STRR-M3	3000	3000	13" diameter reel
VS-8EWF06S-M3	75	3000	Antistatic plastic tubes
VS-8EWF06STR-M3	2000	2000	13" diameter reel
VS-8EWF06STRL-M3	3000	3000	13" diameter reel
VS-8EWF06STRR-M3	3000	3000	13" diameter reel

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95016">www.vishay.com/doc?95016</a>
Part marking information	<a href="http://www.vishay.com/doc?95176">www.vishay.com/doc?95176</a>
Packaging information	<a href="http://www.vishay.com/doc?95033">www.vishay.com/doc?95033</a>

## D-PAK (TO-252AA)



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
c	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
E	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
e	2.29 BSC		0.090 BSC		
H	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51 BSC		0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

**Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**



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(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

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ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

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Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А